FET Input 350MHz Buffer



CLM4133 / CLM4333

FEATURES

| | Slew Rate | 600 | 0V /į | μS |
|---|-------------------------|------------|------------------|--------------|
| Ξ | Wide Benduidth | ~- | ~ | |
| | Wide Bandwidth DC | | | |
| • | Low Phase Non-Linearity | ٠. | | 2 |
| • | Fast Rise Times | | 1.0 | ns |
| • | Fast Rise Times | . ' | 10 ¹⁰ | $\Omega^{(}$ |

APPLICATIONS

- High Speed ATE
- Coaxial Cable Driver
- Isolation Buffer
- High Speed S/H Amplifier
- High Frequency Filter
- Flash A/D Buffer

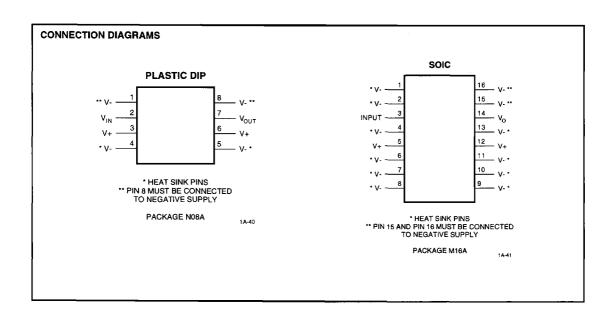
GENERAL DESCRIPTION

The CLM4133 is a high speed, FET input, voltage follower/buffer designed to provide frequencies from DC to over 350MHz and slew rates of 6000V/μs.

The family is intended to fulfill a wide range of buffer applications such as high speed line drivers, video impedance transformation, nuclear instrumentation amplifiers, op amp isolation buffer for driving reactive loads and high impedance input buffers for high speed ADCs and comparators.

ORDERING INFORMATION

| Part | Package | Temperature Range |
|----------|-------------------------|---------------------|
| CLM4133N | NO8A (Plastic PDip 8 Le | ad) -40°C to +85°C |
| CLM4333N | NO8A (Plastic PDip 8 Le | ead) -40°C to +85°C |
| CLM4133M | M16A (SOIC 16 Lead) | -40°C to +85°C |
| CLM4333M | M16A (SOIC 16 Lead) | -40°C to +85°C |





ABSOLUTE MAXIMUM RATINGS (Note 1)

| Supply Voltage ±20 | ESD Tolerance (Note 3) ±2000V |
|---|-----------------------------------|
| Input Voltage ±Vsupply | Thermal Resistance (θJA) (Note 6) |
| Storage Temperature Range65°C to +150°C | N Package 50°C/W |
| Lead Temperature | M Package 60°C/W |
| (Soldering 10 seconds) | Maximum Junction Temperature |
| Power Dissipation (Note 4) | • |

DC ELECTRICAL CHARACTERISTICS

The following specifications apply for Supply Voltage = $\pm 15V$, $V_{CM}=0$, $R_L \geq 100K\Omega$ and $R_S=50\Omega$ unless otherwise noted. **Boldface** limits apply for $T_A=T_J=T_{MIN}$ to T_{MAX} ; all other limits $T_A=T_J=25^{\circ}C$.

| _ | CHARACTERISTICS | ТҮР | CLM4133 | CLM4333 | UNITS | |
|-----------------|---------------------------------|------------------|-----------------------|-----------------------|------------|--|
| SYMBOL. | | | Limit (Note 5) | Limit (Note 5) | | CONDITIONS |
| Av1 | Voltage Gain 1 | 0.980 | 0.960 0.950 | 0.950 0.950 | V/V Min | $R_L = 1K\Omega$, $V_{IN} = \pm 10V$ |
| A _{V2} | Voltage Gain 2 | 0.900 | 0.800 0.800 | 0.800 0.800 | V/V (VIII) | $R_L = 50\Omega$, $V_{IN} = \pm 6V$ |
| Vos | Offset Voltage | 15 | 25 | 45 | mV Max | $R_L = 1K\Omega (T_A = 25^{\circ}C, Note 7)$ |
| IB | Input Bias Current | 1 | 350 | 750 | pA Max | $R_L = 1K\Omega$, $R_S = 10k\Omega$ |
| Rin | Input Resistance | 10 ¹⁰ | 10 ¹⁰ | 10 ¹⁰ | Ω | $R_L = 50\Omega$ |
| CiN | Input Capacitance | 3.0 | | | pF | |
| Ro | Output Resistance | 3 | 10 | 10 | Ω Max | Iout = ±10mA |
| ls ₁ | Supply Current 1 | 14 | 18 | 20 | mA Max | R _L = ∞ |
| V ₀₁ | Output Swing 1 | 13.5 | 12 11 | 12 11 | ±V Min | R _L = 1K |
| V _{O2} | Output Swing 2 | 12.5 | 10 9 | 10 9 | ±Α ΙΛΙΙΝ | R _L = 100Ω |
| Іоит | Output Current | 200 | 100 | 100 | mA | V _{IN} = ±13V |
| PSSR | Power Supply Rejection Ratio | 70 | 60 60 | 60 60 | dB Min | $V^{\pm} = \pm 5V \text{ to } \pm 15V$ |



AC ELECTRICAL CHARACTERISTICS

The following specifications apply for Supply Voltage = $\pm 15V$, $V_{CM} = 0$, $R_L \ge 100 K\Omega$ and $R_S = 50\Omega$ unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}C$.

| SYMBOL | CHARACTERISTICS | ТҮР | CLM4133 | CLM4333 | UNITS | CONDITIONS |
|---------------------------------|------------------------|------|----------------|----------------|-------|---|
| 0502 | | | Limit (Note 5) | Limit (Note 5) | | CONDITIONS |
| SR ₁ | Slew Rate 1 | 6000 | 4000 | 3000 | V/µs | V _{IN} = ±11V, R _L = 1KΩ (Note 2) |
| SR ₂ | Slew Rate 2 | 3000 | 2000 | 1000 | V/μs | V _{IN} = ±7V, R _L = 50Ω (Note 2) |
| SS _{BW} | Small Signal Bandwidth | 350 | 240 | 180 | | $V_{\text{IN}} = \pm 100 \text{mV}_{\text{PP}}, \ R_{L} = 50 \Omega$ $C_{L} \le 10 \text{pF}$ |
| LS _{BW} | Large Signal Bandwidth | 95 | 60 | 40 | MHz | V _{IN} = ±11V, R _L = 1K C _L ≤ 10pF |
| Рвw | Power Bandwidth | 70 | 45 | 20 | | V_{IN} = ±8V, R_L = 50 Ω $C_L \le 10pF$ |
| t _r , t _f | Rise Time Fall Time | 1.0 | 1.5 | 4.0 | ns | $\begin{aligned} R_L &= 50\Omega, \ C_L \leq 10 pF \\ V_O &= 100 mV_{PP} \end{aligned}$ |
| t _{pd} | Propagation Delay Time | 1.5 | | | ns | $R_L = 50\Omega$, $C_L \le 10pF$ $V_O = 100mV_{PP}$ |

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions.

Note 2: Slew rate is measured with 50Ω source impedance at 25° C. For accurate measurements, the input slew rate should be at least $8000V/\mu s$.

Note 3: The test circuit consists of the human body model of 120pF in series with 1500 Ω .

Note 4: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$.

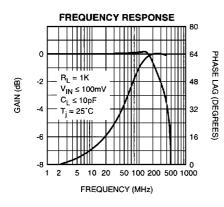
Note 5: Limits are guaranteed by testing, correlation or periodic characterization.

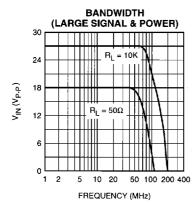
Note 6: For M & N package, θ_{JA} is measured by soldering the unit directly on a printed circuit board and V' pins are connected to 2 square inches of 2 oz copper.

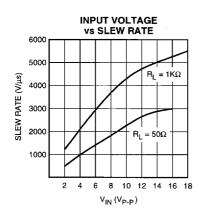
Note 7: T_A = 25°C, after 2 minutes of power in still air.

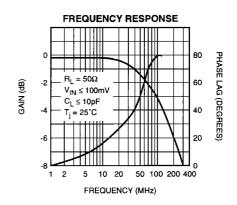


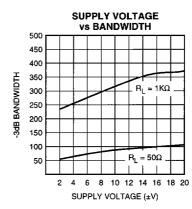


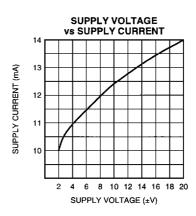




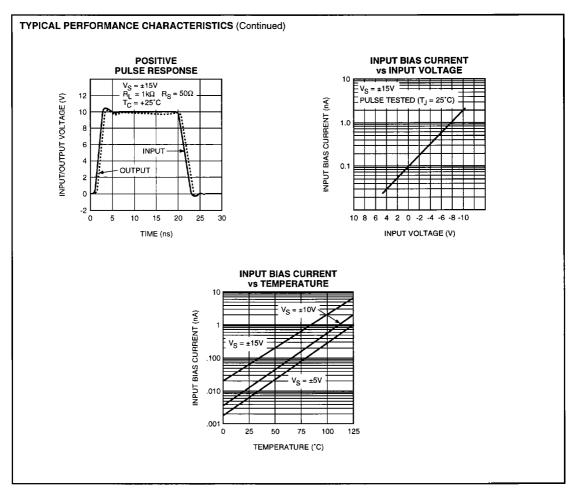














APPLICATION HINTS

Recommended Layout Precautions

RF/video printed circuit board layout rules should be followed when using the CLM4133 since the product will provide power gain to frequencies over 200MHz. Ground planes are recommended and power supplies should be decoupled at each device with low inductance capacitors.

Operation from Single or Asymmetrical Power Supplies

The CLM4133 may be readily used in applications where symmetrical supplies are unavailable or not desirable. A typical application might be an interface to a MOS shift register where $V^+ = +5V$ and $V^- = -12V$. In this case, an apparent output offset occurs due to the device's voltage gain of less than unity. This additional output offset error may be predicted by:

$$\Delta V_0 \cong (1 - A_V) \frac{(V^+ - V^-)}{2} = 0.005 (V^+ - V^-)$$

where:

Ay = No load voltage gain, typically 0.99

V⁺ = Positive supply voltage V⁻ = Negative supply voltage

For the above example, ΔV_O would be -35mV. This may be adjusted to zero by offset voltage adjustment described earlier. For AC coupled applications, no additional offset occurs if the DC input is properly biased as illustrated in the "typical applications" section.

Capacitance Loading

The CLM4133/4233/4333 are designed to drive capacitive loads such as coaxial cables in excess of several thousand picofarads without susceptibility to oscillation. However, peak current resulting from (CdV/dt) should be limited below absolute maximum peak current ratings for the devices.

Thus for the CLM4133 family:

$$\left(\frac{\Delta V_{IN}}{\Delta t}\right) \times C_L \le I_{OUT} \le \pm 250 \text{mA}$$

In addition, power dissipation resulting from driving capacitive loads plus standby power should be kept below total package rating:

$$\begin{array}{l} P_{diss\,pkg} \, \geq P_{DC} + P_{AC} \\ \geq (V^+ - V^-) \times I_S + P_{AC} \\ P_{AC} \cong (V_{P-P})^2 \times f \times C_L \end{array}$$

where:

V_{P-P} = Peak-to-peak output voltage swing f = Frequency C_L = Load Capacitance

Operation Within an Op Amp Loop

The CLM4133 family may be used as a current booster or isolation buffer within a closed loop with op amps such as LH0032, CLM4132, or CLM4124. An isolation resistor of 47Ω should be used between the op amp output and the input of CLM4133. The wide bandwidths and high slew rates of the CLM4133 assures that the loop has the characteristics of the op amp and that additional rolloff is not required

Hardware

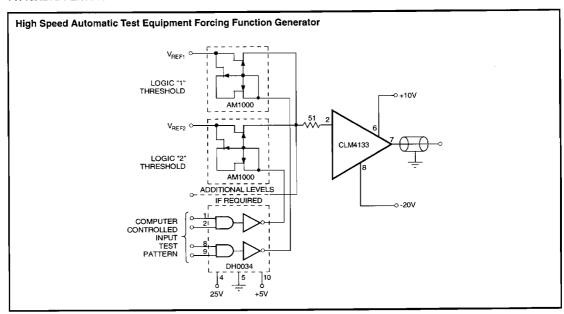
In order to utilize the full drive capabilities of the CLM4133, the device should be mounted with a heat sink particularly for extended temperature operation.

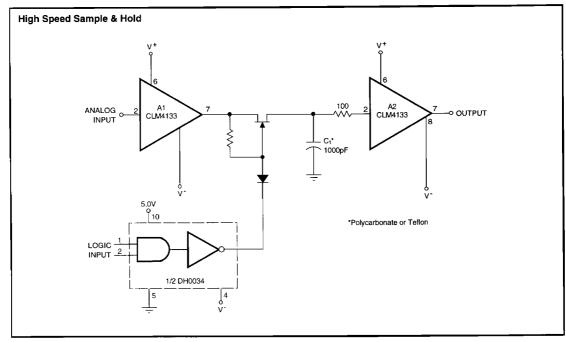
DESIGN PRECAUTION

Power supply bypassing is necessary to prevent oscillation in the CLM4133 in all circuits. Low inductance ceramic disc capacitors with the shortest practical lead lengths must be connected from each supply lead (within < 1/4" to 1/2" of the device package) to a ground plane. Capacitors should be one or two $0.1\mu F$ in parallel for the CLM4133; adding a $4.7\mu F$ solid tantalum capacitor will help in troublesome instances.



TYPICAL APPLICATIONS







TYPICAL APPLICATIONS (Continued)

